

Data sheet acquired from Harris Semiconductor SCHS249B

August 1998 - Revised July 2002

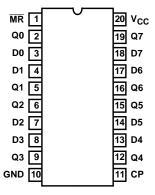
# Octal D Flip-Flop with Reset

### Features

- Buffered Inputs
- · Typical Propagation Delay
  - 6.5ns at  $V_{CC} = 5V$ ,  $T_A = 25^{\circ}C$ ,  $C_L = 50pF$
- Exceeds 2kV ESD Protection MIL-STD-883, Method 3015
- SCR-Latchup-Resistant CMOS Process and Circuit Design
- Speed of Bipolar FAST™/AS/S with Significantly Reduced Power Consumption
- Balanced Propagation Delays
- AC Types Feature 1.5V to 5.5V Operation and Balanced Noise Immunity at 30% of the Supply
- ±24mA Output Drive Current
  - Fanout to 15 FAST™ ICs
  - Drives  $50\Omega$  Transmission Lines

### **Pinout**

CD54AC273, CD54ACT273 (CDIP) CD74AC273, CD74ACT273 (PDIP, SOIC) TOP VIEW



### Description

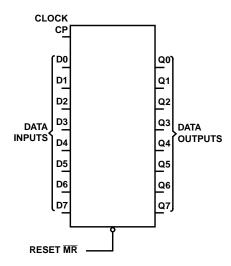
The 'AC273 and 'ACT273 devices are octal D-type flip-flops with reset that utilize advanced CMOS logic technology. Information at the D input is transferred to the Q output on the positive-going edge of the clock pulse. All eight flip-flops are controlled by a common clock (CP) and a common reset ( $\overline{\text{MR}}$ ). Resetting is accomplished by a low voltage level independent of the clock.

### **Ordering Information**

PART NUMBER	TEMPERATURE RANGE	PACKAGE
CD74AC273E	0°C to 70°C -40°C to 85°C -55°C to 125°C	20 Ld PDIP
CD54AC273F3A	-55°C to 125°C	20 Ld CDIP
CD74ACT273E	0°C to 70°C -40°C to 85°C -55°C to 125°C	20 Ld PDIP
CD54ACT273F3A	-55 <sup>0</sup> C to 125 <sup>0</sup> C	20 Ld CDIP
CD74AC273M	0°C to 70°C -40°C to 85°C -55°C to 125°C	20 Ld SOIC
CD74ACT273M	0°C to 70°C -40°C to 85°C -55°C to 125°C	20 Ld SOIC

- 1. When ordering, use the entire part number. Add the suffix 96 to obtain the variant in the tape and reel.
- Wafer and die for this part number is available which meets all electrical specifications. Please contact your local sales office for ordering information.

# Functional Diagram



**TRUTH TABLE** 

	OUTPUTS		
RESET (MR)	CLOCK CP	DATA Dn	Qn
L	Х	Х	L
Н	<b>↑</b>	Н	Н
Н	1	L	L
Н	L	Х	Q0

### **Absolute Maximum Ratings**

DC Supply Voltage, V <sub>CC</sub> 0.	5V to 6V
DC Input Diode Current, I <sub>IK</sub>	
For $V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$	.±20mA
DC Output Diode Current, IOK	
For $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$	.±50mA
DC Output Source or Sink Current per Output Pin, IO	
For $V_O > -0.5V$ or $V_O < V_{CC} + 0.5V$	.±50mA
DC V <sub>CC</sub> or Ground Current, I <sub>CC or</sub> I <sub>GND</sub> (Note 3)	±100mA

### **Thermal Information**

Thermal Resistance, $\theta_{JA}$ (Typical, Note 5)
E Package
M Package58°C/W
Maximum Junction Temperature (Plastic Package) 150°C
Maximum Storage Temperature Range65°C to 150°C
Maximum Lead Temperature (Soldering 10s)300°C

### **Operating Conditions**

Temperature Range, T <sub>A</sub>
Supply Voltage Range, V <sub>CC</sub> (Note 4)
AC Types
ACT Types
DC Input or Output Voltage, V <sub>I</sub> , V <sub>O</sub> 0V to V <sub>CC</sub>
Input Rise and Fall Slew Rate, dt/dv
AC Types, 1.5V to 3V 50ns (Max)
AC Types, 3.6V to 5.5V
ACT Types, 4.5V to 5.5V

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

### NOTES:

- 3. For up to 4 outputs per device, add  $\pm 25 \text{mA}$  for each additional output.
- 4. Unless otherwise specified, all voltages are referenced to ground.
- 5. The package thermal impedance is calculated in accordance with JESD 51.

### **DC Electrical Specifications**

		TEST CONDITIONS		v <sub>cc</sub>	25	o°C		C TO °C		C TO 5°C	
PARAMETER	SYMBOL	V <sub>I</sub> (V)	I <sub>O</sub> (mA)	(V)	MIN	MAX	MIN	MAX	MIN	MAX	UNITS
AC TYPES											
High Level Input Voltage	V <sub>IH</sub>	-	-	1.5	1.2	-	1.2	-	1.2	-	V
				3	2.1	-	2.1	-	2.1	-	V
				5.5	3.85	-	3.85	-	3.85	-	V
Low Level Input Voltage	V <sub>IL</sub>	-	-	1.5	-	0.3	-	0.3	-	0.3	V
				3	-	0.9	-	0.9	-	0.9	V
				5.5	-	1.65	-	1.65	-	1.65	V
High Level Output Voltage	V <sub>OH</sub>	V <sub>IH</sub> or V <sub>IL</sub>	-0.05	1.5	1.4	-	1.4	-	1.4	-	V
			-0.05	3	2.9	-	2.9	-	2.9	-	V
			-0.05	4.5	4.4	-	4.4	-	4.4	-	V
			-4	3	2.58	-	2.48	-	2.4	-	V
			-24	4.5	3.94	-	3.8	-	3.7	-	V
			-75 (Note 6, 7)	5.5	-	-	3.85	-	-	-	V
			-50 (Note 6, 7)	5.5	-	-	-	-	3.85	-	V

### DC Electrical Specifications (Continued)

			ST ITIONS	v <sub>cc</sub>	25	25°C		C TO °C	-55°C TO 125°C		
PARAMETER	SYMBOL	V <sub>I</sub> (V)	I <sub>O</sub> (mA)	(v)	MIN	MAX	MIN	MAX	MIN	MAX	UNITS
Low Level Output Voltage	$V_{OL}$	V <sub>IH</sub> or V <sub>IL</sub>	0.05	1.5	-	0.1	-	0.1	-	0.1	V
			0.05	3	-	0.1	-	0.1	-	0.1	V
			0.05	4.5	-	0.1	-	0.1	-	0.1	V
			12	3	-	0.36	-	0.44	-	0.5	V
			24	4.5	-	0.36	-	0.44	-	0.5	V
			75 (Note 6, 7)	5.5	-	-	-	1.65	-	-	V
			50 (Note 6, 7)	5.5	-	-	-	-	-	1.65	V
Input Leakage Current	lį	V <sub>CC</sub> or GND	-	5.5	-	±0.1	-	±1	-	±1	μА
Quiescent Supply Current MSI	I <sub>CC</sub>	V <sub>CC</sub> or GND	0	5.5	-	8	-	80	-	160	μА
ACT TYPES											
High Level Input Voltage	V <sub>IH</sub>	-	-	4.5 to 5.5	2	-	2	-	2	-	V
Low Level Input Voltage	V <sub>IL</sub>	-	-	4.5 to 5.5	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage	V <sub>OH</sub>	V <sub>IH</sub> or V <sub>IL</sub>	-0.05	4.5	4.4	-	4.4	-	4.4	-	V
			-24	4.5	3.94	-	3.8	-	3.7	-	V
			-75 (Note 6, 7)	5.5	-	-	3.85	-	-	-	V
			-50 (Note 6, 7)	5.5	-	-	-	-	3.85	-	V
Low Level Output Voltage	V <sub>OL</sub>	V <sub>IH</sub> or V <sub>IL</sub>	0.05	4.5	-	0.1	-	0.1	-	0.1	V
			24	4.5	-	0.36	-	0.44	-	0.5	V
			75 (Note 6, 7)	5.5	-	-	-	1.65	-	-	V
			50 (Note 6, 7)	5.5	-	-	-	-	-	1.65	V
Input Leakage Current	lį	V <sub>CC</sub> or GND	-	5.5	-	±0.1	-	±1	-	±1	μΑ
Quiescent Supply Current MSI	Icc	V <sub>CC</sub> or GND	0	5.5	-	8	-	80	-	160	μΑ
Additional Supply Current per Input Pin TTL Inputs High 1 Unit Load	Δl <sub>CC</sub>	V <sub>CC</sub> -2.1	-	4.5 to 5.5	-	2.4	-	2.8	-	3	mA

### NOTES:

- 6. Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize power dissipation.
- 7. Test verifies a minimum  $50\Omega$  transmission-line-drive capability at  $85^{\circ}$ C,  $75\Omega$  at  $125^{\circ}$ C.

## **ACT Input Load Table**

INPUT	UNIT LOAD
Dn	0.5
MR	0.57
СР	1

NOTE: Unit load is  $\Delta I_{CC}$  limit specified in DC Electrical Specifications Table, e.g., 2.4mA max at  $25^{\rm o}C.$ 

# **Prerequisite For Switching Function**

			-40°C	ГО 85°C	-55°C T		
PARAMETER	SYMBOL	V <sub>CC</sub> (V)	MIN	MAX	MIN	MAX	UNITS
AC TYPES							
Data to CP Set-Up Time	t <sub>SU</sub>	1.5	2	-	2	-	ns
		3.3 (Note 9)	2	-	2	-	ns
		5 (Note 10)	2	-	2	-	ns
Hold Time	t <sub>H</sub>	1.5	2	-	2	-	ns
		3.3	2	-	2	-	ns
		5	2	-	2	-	ns
Removal Time, MR to CP	t <sub>REM</sub>	1.5	2	-	2	-	ns
		3.3	2	-	2	-	ns
		5	2	-	2	-	ns
MR Pulse Width	t <sub>W</sub>	1.5	55	-	63	-	ns
		3.3	6.1	-	7	-	ns
		5	4.4	-	5	-	ns
CP Pulse Width	t <sub>W</sub>	1.5	55	-	63	-	ns
		3.3	6.1	-	7	-	ns
		5	4.4	-	5	-	ns
CP Frequency	f <sub>MAX</sub>	1.5	9	-	8	-	MHz
		3.3	81	-	71	-	MHz
		5	114	-	100	-	MHz
ACT TYPES	•						
Data to CP Set-Up Time	<sup>t</sup> su	5 (Note 10)	2	-	2	-	ns
Hold Time	t <sub>H</sub>	5	2	-	2	-	ns
Removal Time MR to CP	t <sub>REM</sub>	5	2	-	2	-	ns
MR Pulse Width	t <sub>W</sub>	5	4.4	-	5	-	ns
CP Pulse Width	t <sub>W</sub>	5	5.3	-	6	-	ns
CP Frequency	f <sub>MAX</sub>	5	97	-	85	-	MHz

# **Switching Specifications** Input $t_r$ , $t_f$ = 3ns, $C_L$ = 50pF (Worst Case)

			-40°C TO 85°C		-55°C TO 125°C				
PARAMETER	SYMBOL	V <sub>CC</sub> (V)	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
AC TYPES									
Propagation Delay,	t <sub>PLH</sub> , t <sub>PHL</sub>	1.5	-	-	154	-	-	169	ns
CP to Qn		3.3 (Note 9)	4.9	-	17.2	4.7	-	18.9	ns
		5 (Note 10)	3.5	-	12.3	3.4	-	13.5	ns

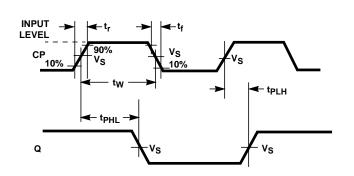
### Switching Specifications Input $t_r$ , $t_f = 3ns$ , $C_L = 50pF$ (Worst Case) (Continued)

			-40°C TO 85°C		-55				
PARAMETER	SYMBOL	V <sub>CC</sub> (V)	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
Propagation Delay,	t <sub>PLH</sub> , t <sub>PHL</sub>	1.5	-	-	154	-	-	169	ns
MR to Qn		3.3	4.9	-	17.2	4.7	-	18.9	ns
		5	3.5	-	12.3	3.4	-	13.5	ns
Input Capacitance	Cl	-	-	-	10	-	-	10	pF
Power Dissipation Capacitance	C <sub>PD</sub> (Note 11)	-	-	45	-	-	45	-	pF
ACT TYPES									
Propagation Delay, CP to Qn	t <sub>PLH</sub> , t <sub>PHL</sub>	5 (Note 10)	3.5	-	12.3	3.4	-	13.5	ns
Propagation Delay, MR to Qn	<sup>t</sup> PLH <sup>,</sup> <sup>t</sup> PHL	5	3.5	-	12.3	3.4	-	13.5	ns
Input Capacitance	Cl	-	-	-	10	-	-	10	pF
Power Dissipation Capacitance	C <sub>PD</sub> (Note 11)	-	-	45	-	-	45	-	pF

### NOTES:

- 8. Limits tested 100%.
- 9. 3.3V Min is at 3.6V, Max is at 3V.
- 10. 5V Min is at 5.5V, Max is at 4.5V.

11.  $C_{PD}$  is used to determine the dynamic power consumption per flip-flop. AC:  $P_D = C_{PD} \ V_{CC}^2 f_j = \sum (C_L \ V_{CC}^2 f_0)$  ACT:  $P_D = C_{PD} \ V_{CC}^2 f_i + \sum (C_L \ V_{CC}^2 f_0) + V_{CC} \ \Delta I_{CC}$  where  $f_i$  = input frequency,  $f_0$  = output frequency,  $C_L$  = output load capacitance,  $V_{CC}$  = supply voltage.



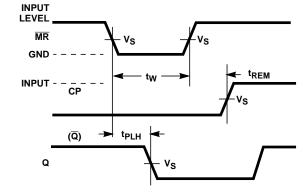


FIGURE 1. PROPAGATION DELAY TIMES AND CLOCK **PULSE WIDTH** 

FIGURE 2. PREREQUISITE AND PROPAGATION DELAY TIMES FOR MASTER RESET

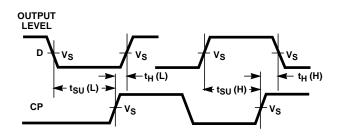
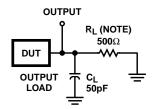


FIGURE 3. PREREQUISITE FOR CLOCK



NOTE: For AC Series Only: When  $V_{\mbox{\footnotesize{CC}}}$  = 1.5V,  $R_L$  = 1k $\!\Omega.$ 

	AC	ACT
Input Level	V <sub>CC</sub>	3V
Input Switching Voltage, V <sub>S</sub>	0.5 V <sub>CC</sub>	1.5V
Output Switching Voltage, V <sub>S</sub>	0.5 V <sub>CC</sub>	0.5 V <sub>CC</sub>

FIGURE 4. PROPAGATION DELAY TIMES

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### **PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CD54AC273F3A	ACTIVE	CDIP	J	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD54AC273F3A	Samples
CD54ACT273F3A	ACTIVE	CDIP	J	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD54ACT273F3A	Samples
CD74AC273E	ACTIVE	PDIP	N	20	20	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74AC273E	Samples
CD74AC273M96	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	AC273M	Samples
CD74ACT273E	ACTIVE	PDIP	N	20	20	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74ACT273E	Samples
CD74ACT273EE4	ACTIVE	PDIP	N	20	20	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74ACT273E	Samples
CD74ACT273M96	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	ACT273M	Samples
CD74ACT273M96E4	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	ACT273M	Samples
CD74ACT273PWR	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HM273	Samples
CD74ACT273SM96	ACTIVE	SSOP	DB	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	ACT273SM	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

# PACKAGE OPTION ADDENDUM

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- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

### OTHER QUALIFIED VERSIONS OF CD54AC273, CD54ACT273, CD74AC273, CD74ACT273:

Catalog: CD74AC273, CD74ACT273

Military: CD54AC273, CD54ACT273

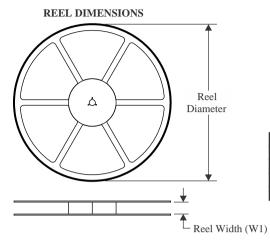
NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

# **PACKAGE MATERIALS INFORMATION**

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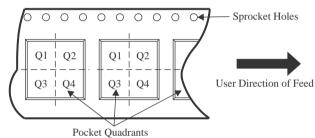
### TAPE AND REEL INFORMATION



# TAPE DIMENSIONS KO P1 BO W Cavity A0

A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

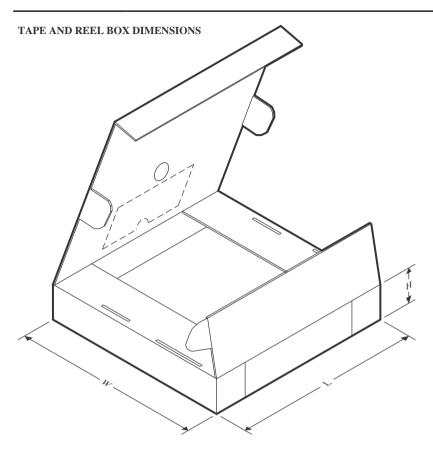


### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74AC273M96	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
CD74ACT273M96	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
CD74ACT273PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
CD74ACT273SM96	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1



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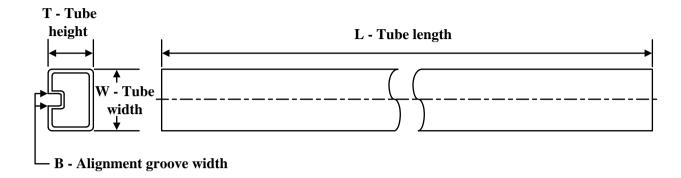
### \*All dimensions are nominal

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
CD74AC273M96	SOIC	DW	20	2000	367.0	367.0	45.0	
CD74ACT273M96	SOIC	DW	20	2000	367.0	367.0	45.0	
CD74ACT273PWR	TSSOP	PW	20	2000	356.0	356.0	35.0	
CD74ACT273SM96	SSOP	DB	20	2000	356.0	356.0	35.0	

# **PACKAGE MATERIALS INFORMATION**

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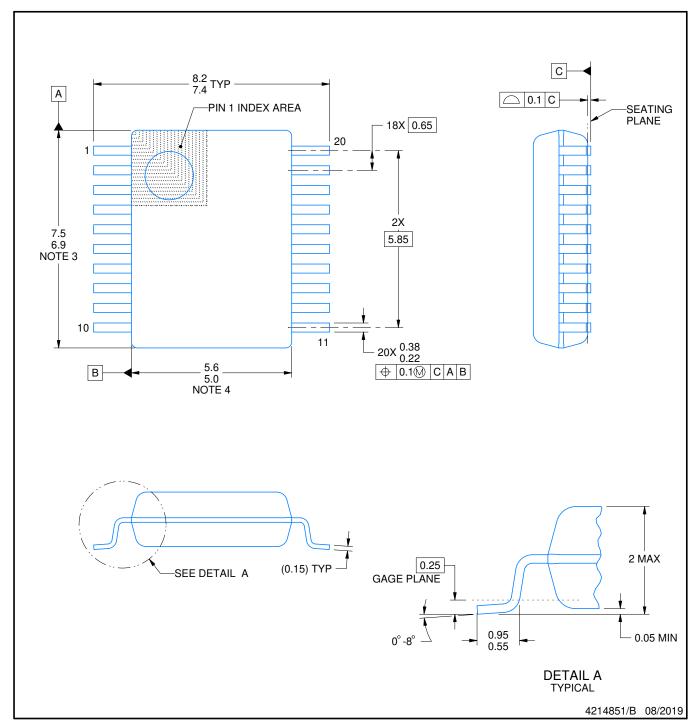
### **TUBE**



### \*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CD74AC273E	N	PDIP	20	20	506	13.97	11230	4.32
CD74ACT273E	N	PDIP	20	20	506	13.97	11230	4.32
CD74ACT273EE4	N	PDIP	20	20	506	13.97	11230	4.32



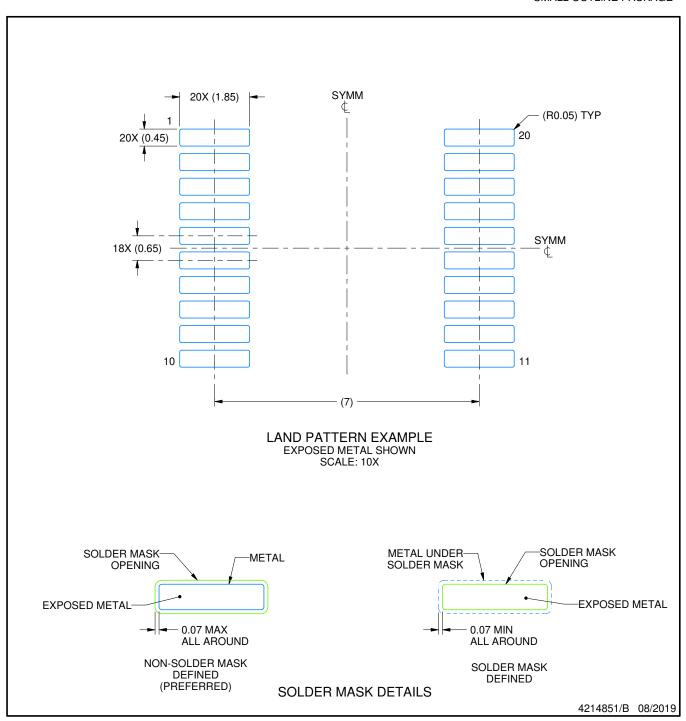


- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.



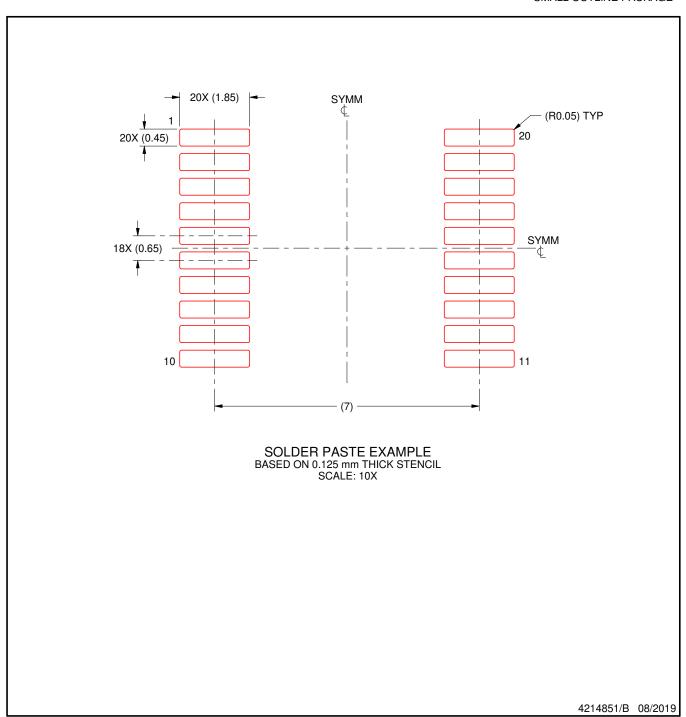


NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



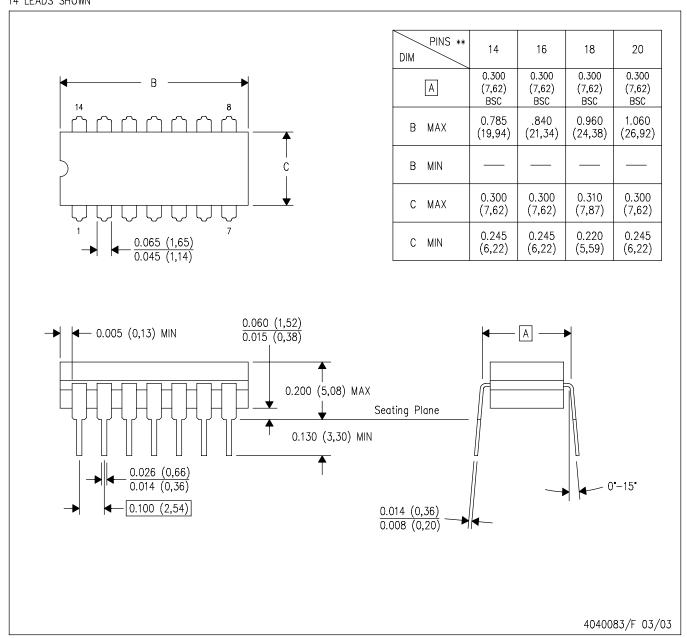


NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



# 14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

# N (R-PDIP-T\*\*)

# PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN

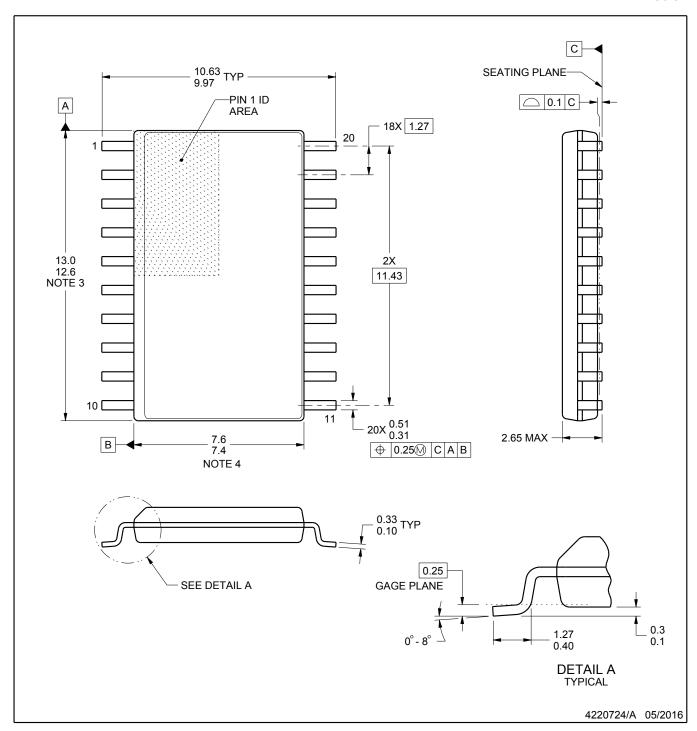


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOIC



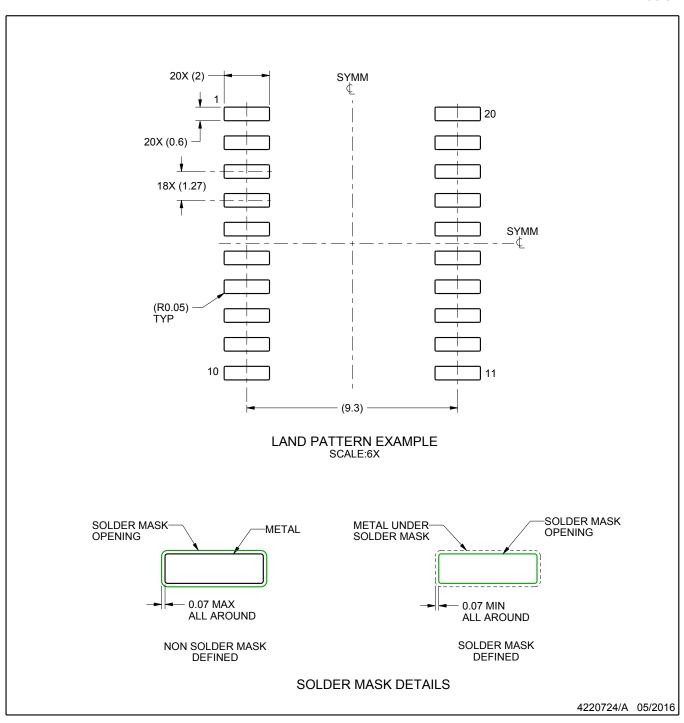
- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



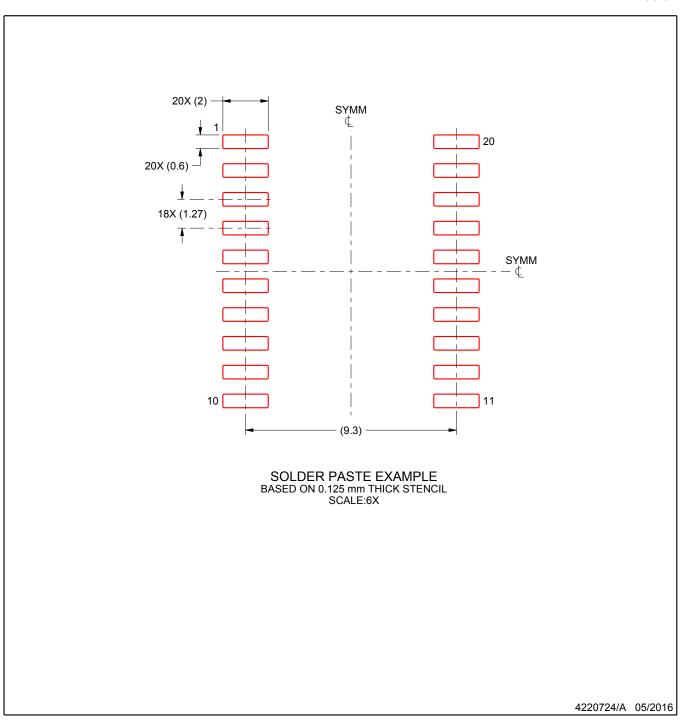
NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC

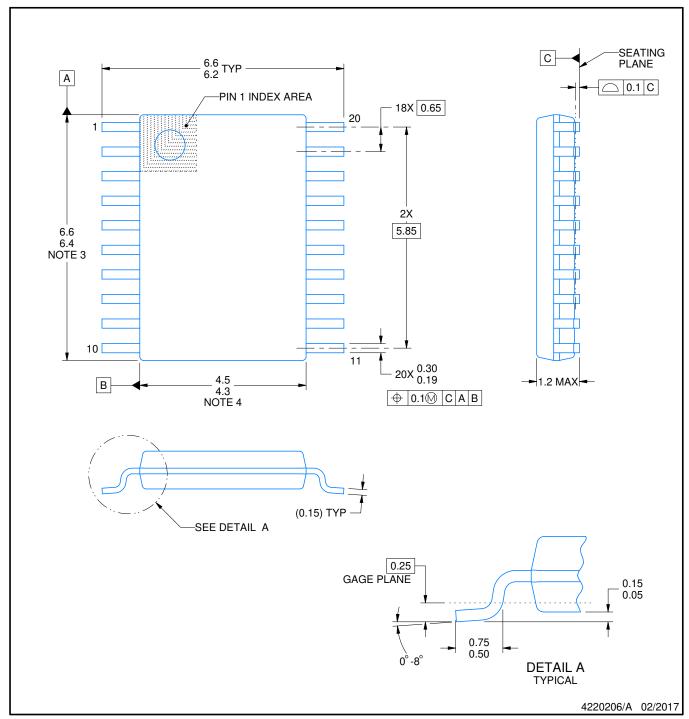


NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





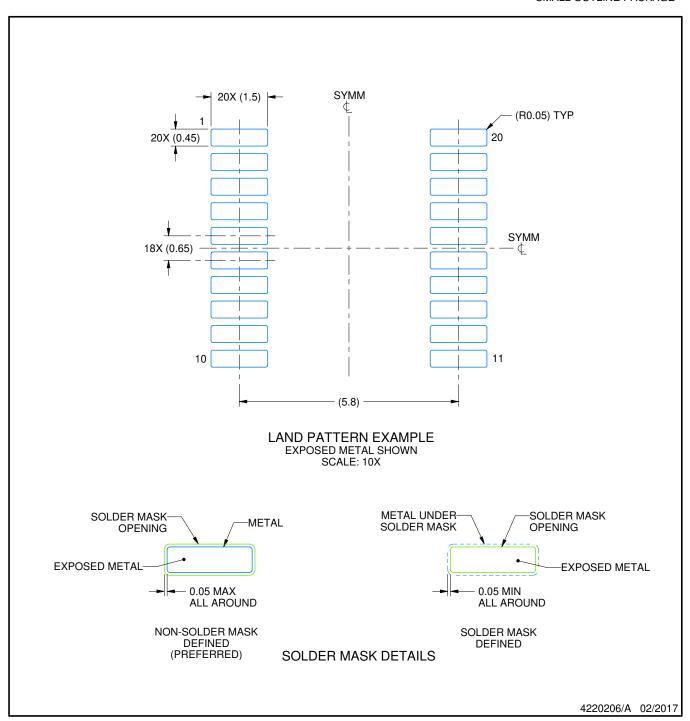


- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



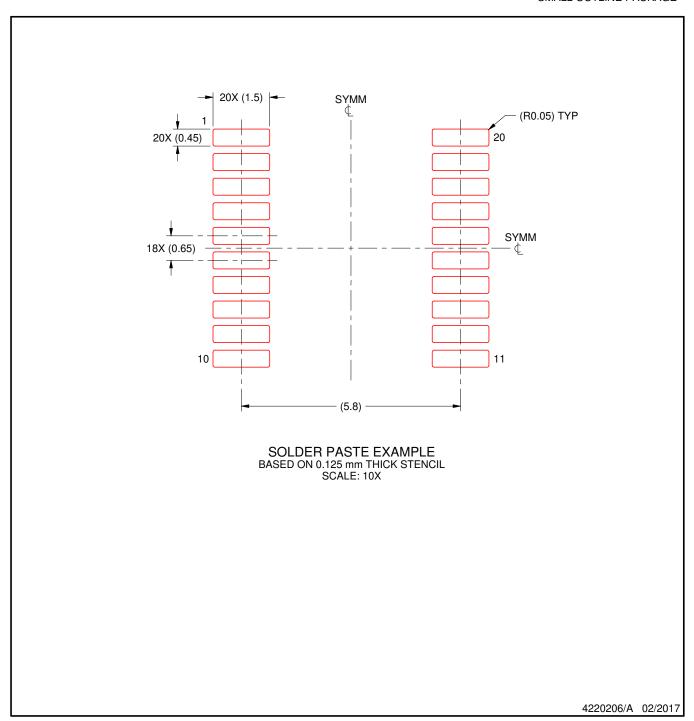


NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





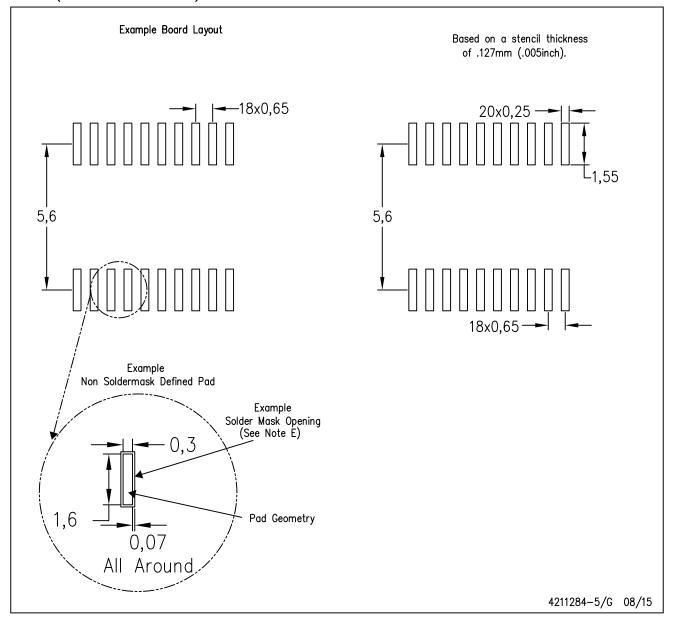
NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



# PW (R-PDSO-G20)

# PLASTIC SMALL OUTLINE



- All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
  C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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